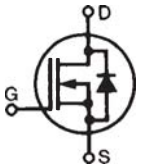
# IXYS

## Depletion Mode MOSFET

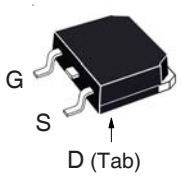
## IXTH10N100D
## IXTT10N100D

$V_{DSX}$ = 1000V
$I_{D25}$ = 10A
$R_{DS(on)}$ ≤ 1.4Ω

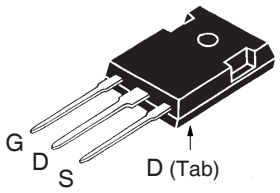
## N-Channel




**TO-268 (IXTT)**




**TO-247 (IXTH)**




G = Gate D = Drain
S = Source Tab = Drain

| Symbol | Test Conditions | Maximum Ratings | |
|---|---|---|---|
| $V_{DSX}$ | $T_J$ = 25°C to 150°C | 1000 | V |
| $V_{DGX}$ | $T_J$ = 25°C to 150°C, $R_{GS}$ = 1MΩ | 1000 | V |
| $V_{GSX}$ | Continuous | ±30 | V |
| $V_{GSM}$ | Transient | ±40 | V |
| $I_{D25}$ | $T_C$ = 25°C | 10 | A |
| $I_{DM}$ | $T_C$ = 25°C, Pulse Width Limited by $T_{JM}$ | 20 | A |
| $P_D$ | $T_C$ = 25°C | 400 | W |
| $T_J$ | | - 55 ... +150 | °C |
| $T_{JM}$ | | 150 | °C |
| $T_{stg}$ | | - 55 ... +150 | °C |
| $T_L$ | Maximum Lead Temperature for Soldering | 300 | °C |
| $T_{SOLD}$ | 1.6 mm (0.062in.) from Case for 10s | 260 | °C |
| $M_d$ | Mounting Torque (TO-247) | 1.13 / 10 | Nm/lb.in. |
| **Weight** | TO-268 | 4 | g |
| | TO-247 | 6 | g |

| Symbol | Test Conditions ($T_J$ = 25°C, Unless Otherwise Specified) | Characteristic Values Min. | Typ. | Max. | |
|---|---|---|---|---|---|
| $BV_{DSX}$ | $V_{GS}$ = -10V, $I_D$ = 250μA | 1000 | | | V |
| $V_{GS(off)}$ | $V_{DS}$ = 25V, $I_D$ = 250μA | -1.5 | | - 3.5 | V |
| $I_{GSX}$ | $V_{GS}$ = ±30V, $V_{DS}$ = 0V | | | ±100 | nA |
| $I_{DSX(off)}$ | $V_{DS}$ = $V_{DSX}$, $V_{GS}$ = -10V | | | 25 | μA |
| | $T_J$ = 125°C | | | 500 | μA |
| $R_{DS(on)}$ | $V_{GS}$ = 10V, $I_D$ = 10A, Note 1 | | | 1.4 | Ω |
| $I_{D(on)}$ | $V_{GS}$ = 0V, $V_{DS}$ = 25V, Note 1 | | 1.0 | | A |

### Features

- Normally ON Mode
- International Standard Packages
- Molding Epoxies meet UL 94 V-0 Flammability Classification

### Advantages

- Easy to Mount
- Space Savings
- High Power Density

### Applications

- Level Shifting
- Triggers
- Solid State Relays
- Current Regulators
- Active Load

| Symbol | Test Conditions ($T_J$ = 25°C, Unless Otherwise Specified) | Characteristic Values Min. | Typ. | Max. | |
|---|---|---|---|---|---|
| $g_{fs}$ | $V_{DS}$ = 30V, $I_D$ = 0.5 • $I_{D25}$, Note 1 | 3.0 | 5.4 | | S |
| $C_{iss}$ | $V_{GS}$ = -10V, $V_{DS}$ = 25V, f = 1MHz | | 2500 | | pF |
| $C_{oss}$ | | | 300 | | pF |
| $C_{rss}$ | | | 100 | | pF |
| $t_{d(on)}$ | **Resistive Switching Times** | | 35 | | ns |
| $t_r$ | $V_{GS}$ = -10V, $V_{DS}$ = 0.5 • $V_{DSX}$, $I_D$ = 0.5 • $I_{D25}$ | | 85 | | ns |
| $t_{d(off)}$ | $R_G$ = 4.7Ω (External) | | 110 | | ns |
| $t_f$ | | | 75 | | ns |
| $Q_{g(on)}$ | $V_{GS}$ = 10V, $V_{DS}$ = 0.5 • $V_{DSX}$, $I_D$ = 0.5 • $I_{D25}$ | | 130 | | nC |
| $Q_{gs}$ | | | 27 | | nC |
| $Q_{gd}$ | | | 58 | | nC |
| $R_{thJC}$ | | | | 0.31 | °C/W |
| $R_{thCS}$ | TO-247 | | 0.21 | | °C/W |

**Source-Drain Diode**

| Symbol | Test Conditions ($T_J$ = 25°C, Unless Otherwise Specified) | Characteristic Values Min. | Typ. | Max. | |
|---|---|---|---|---|---|
| $V_{SD}$ | $I_F$ = $I_{D25}$, $V_{GS}$ = -10V, Note 1 | | 1.1 | 1.5 | V |
| $t_{rr}$ | $I_F$ = 10A, -di/dt = 100A/μs<br>$V_R$ = 100V, $V_{GS}$ = -10V | | 850 | | ns |

Note 1: Pulse test, t ≤ 300μs, duty cycle, d ≤ 2%.

**Fig. 1. Output Characteristics @ $T_J$ = 25°C**

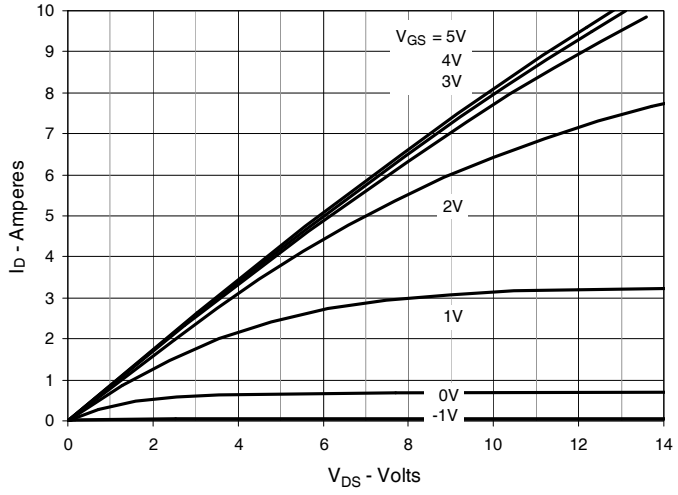



**Fig. 2. Extended Output Characteristics @ $T_J$ = 25°C**

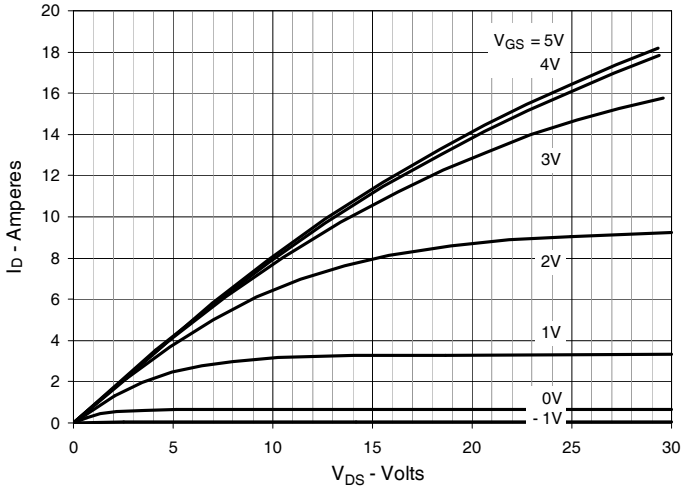



**Fig. 3. Output Characteristics @ $T_J$ = 125°C**

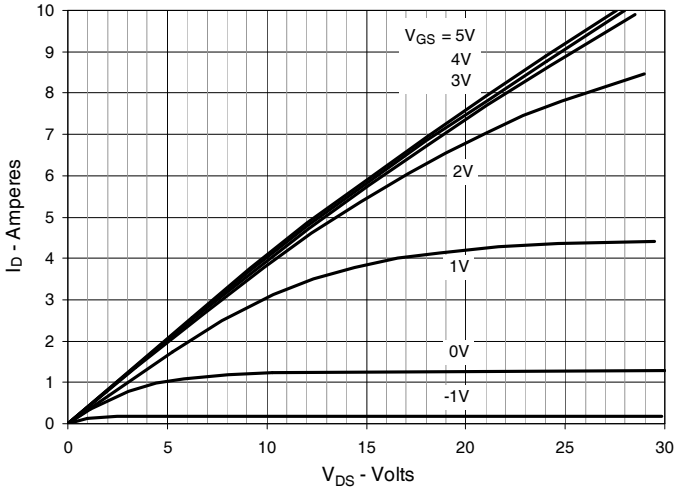



**Fig. 4. $R_{DS(on)}$ Normalized to $I_D$ = 5A Value vs. Junction Temperature**

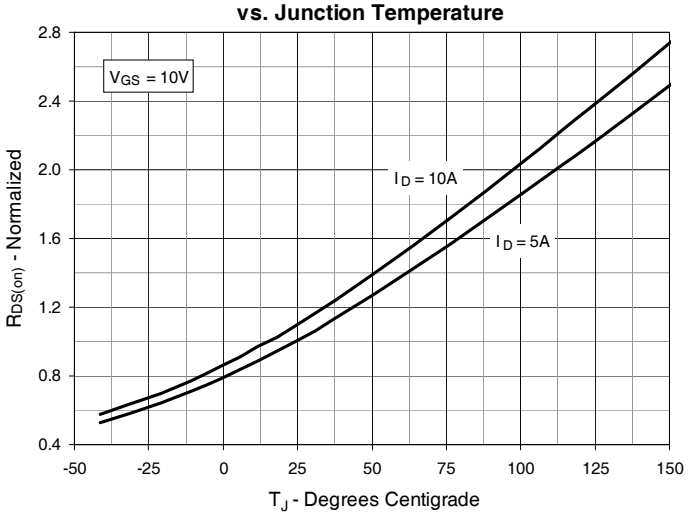



**Fig. 5. $R_{DS(on)}$ Normalized to $I_D$ = 5A Value vs. Drain Current**

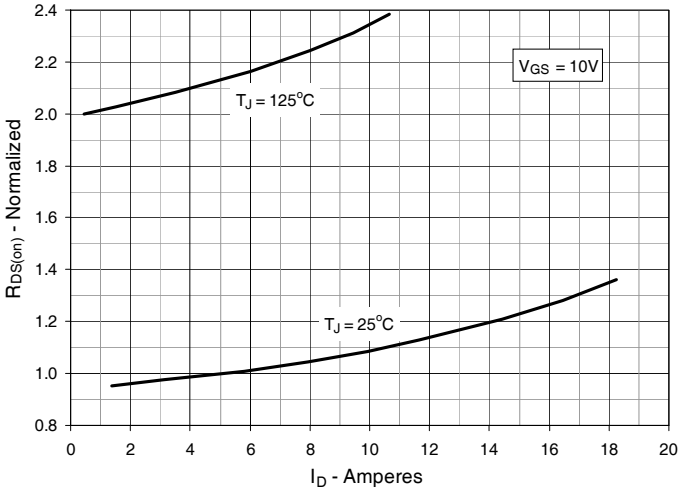



**Fig. 6. Maximum Drain Current vs. Case Temperature**

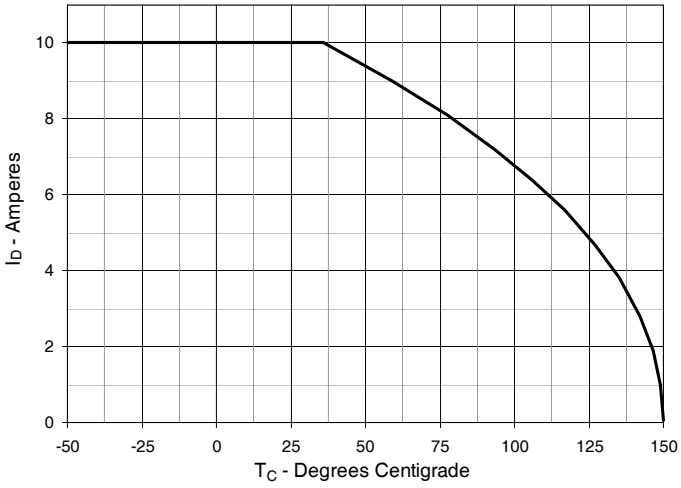


**Fig. 7. Input Admittance**

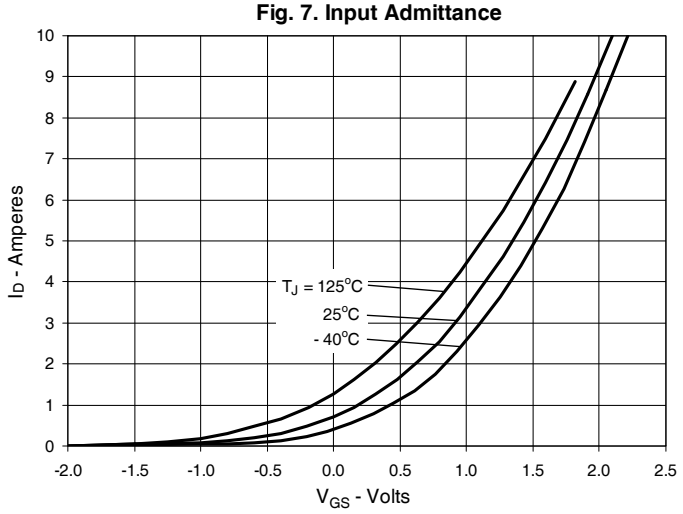



**Fig. 8. Transconductance**

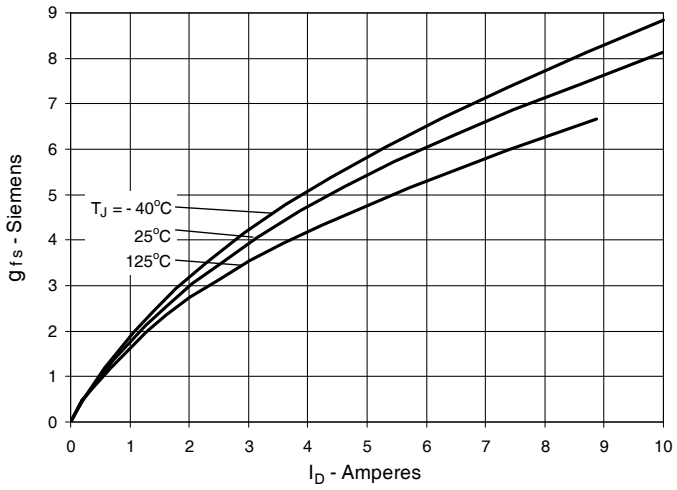



**Fig. 9. Forward Voltage Drop of Intrinsic Diode**

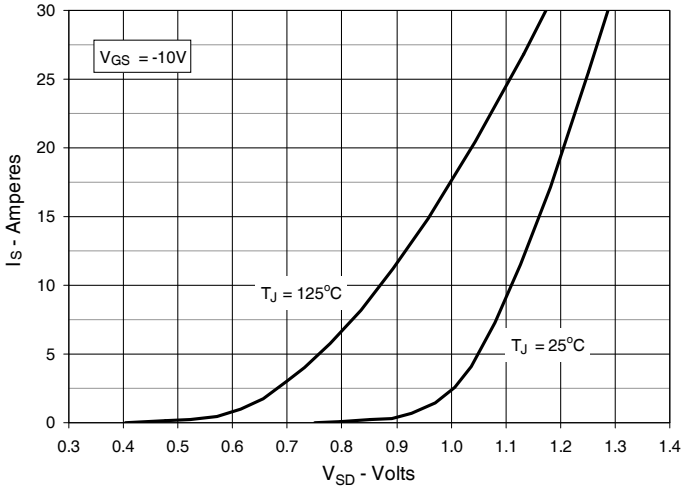



**Fig. 10. Breakdown & Threshold Voltages vs. Junction Temperature**

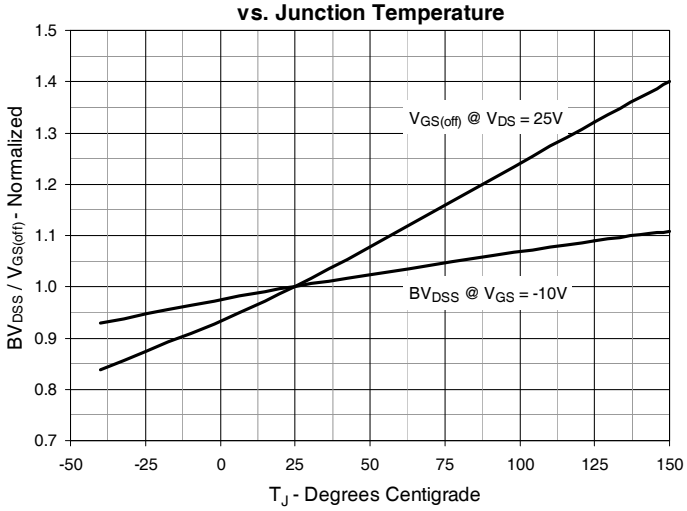



**Fig. 11. Gate Charge**

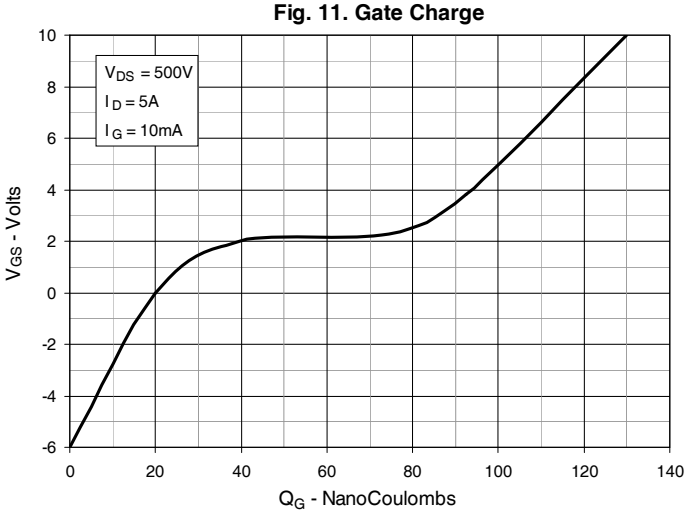



**Fig. 12. Capacitance**

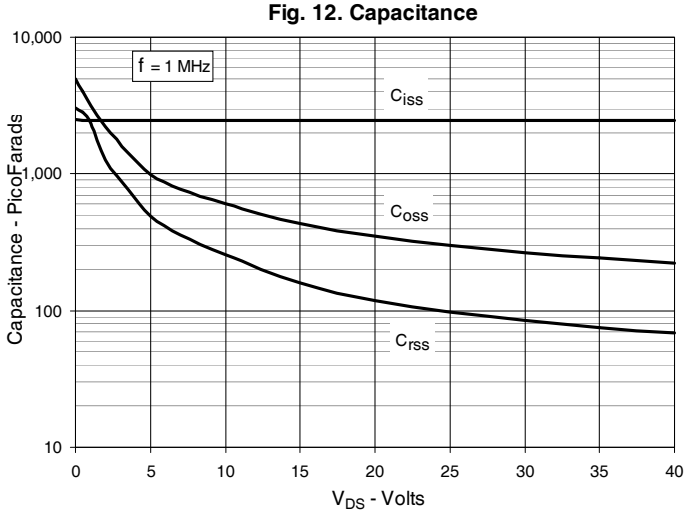


**Fig. 13. Forward-Bias Safe Operating Area @ $T_C$ = 25°C**

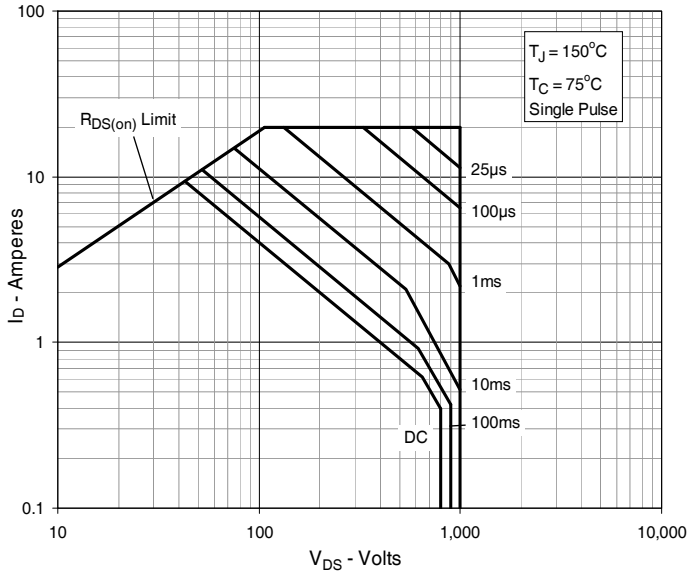



**Fig. 14. Forward-Bias Safe Operating Area @ $T_C$ = 75°C**

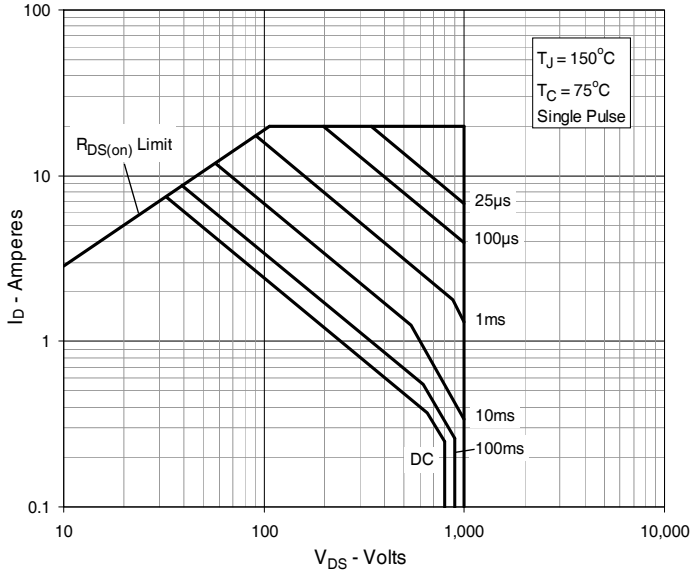
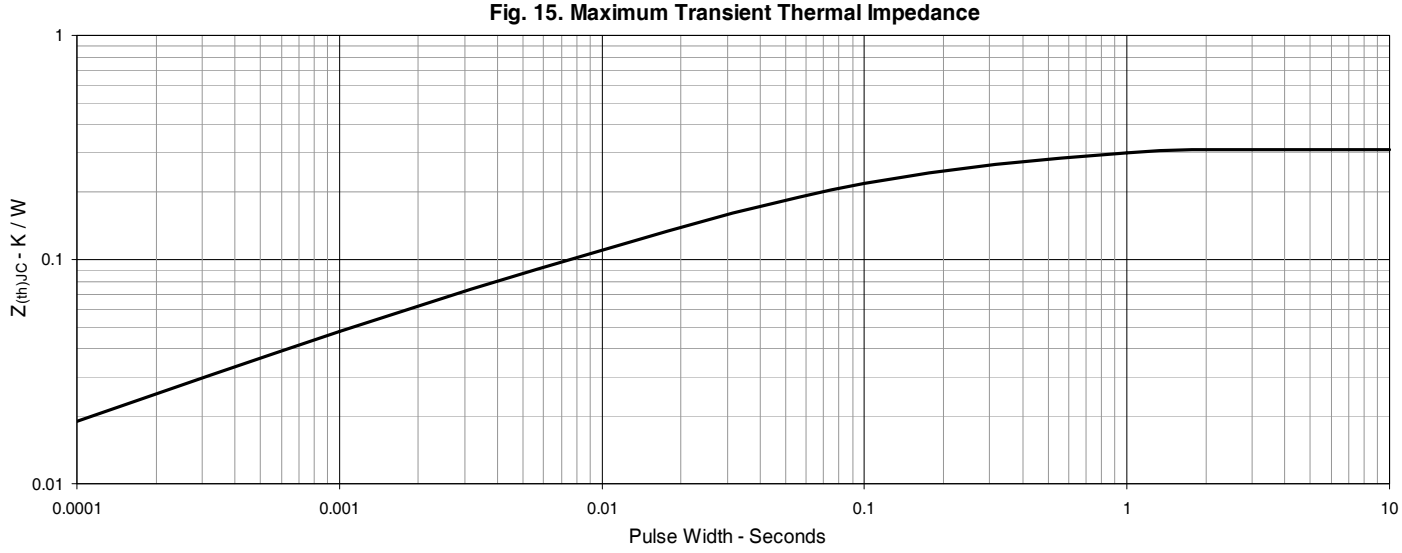
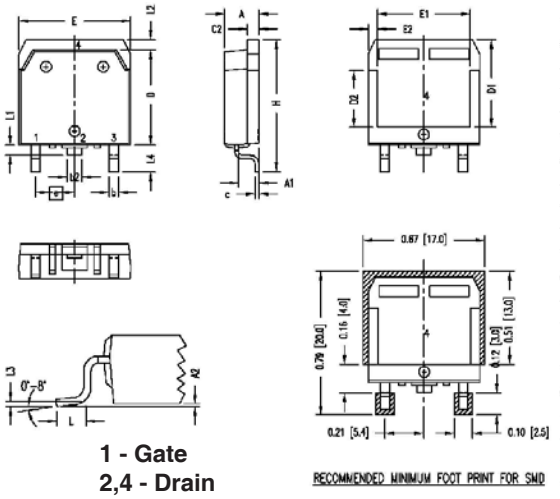



**Fig. 15. Maximum Transient Thermal Impedance**



## TO-268 Outline

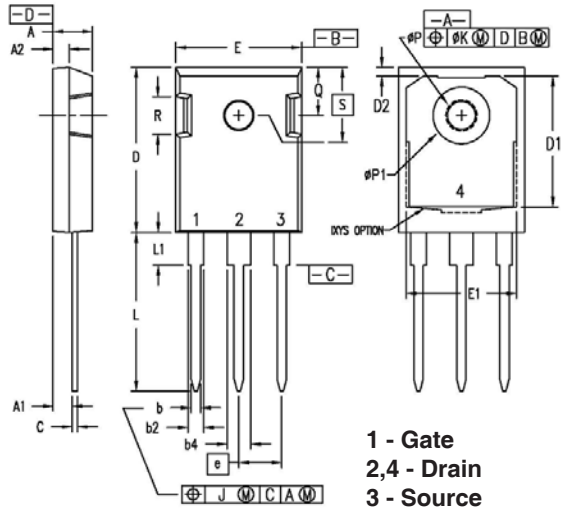



| SYMBOL | INCHES | | MILLIMETERS | |
|---|---|---|---|---|
| | MIN | MAX | MIN | MAX |
| A | .193 | .201 | 4.90 | 5.10 |
| A1 | .106 | .114 | 2.70 | 2.90 |
| A2 | .001 | .010 | 0.02 | 0.25 |
| b | .045 | .057 | 1.15 | 1.45 |
| b2 | .075 | .083 | 1.90 | 2.10 |
| C | .016 | .026 | 0.40 | 0.65 |
| C2 | .057 | .063 | 1.45 | 1.60 |
| D | .543 | .551 | 13.80 | 14.00 |
| D1 | .488 | .500 | 12.40 | 12.70 |
| D2 | .320 | .335 | 8.13 | 8.50 |
| E | .624 | .632 | 15.85 | 16.05 |
| E1 | .524 | .535 | 13.30 | 13.60 |
| E2 | .045 | .055 | 1.14 | 1.39 |
| e | .215 BSC | | 5.45 BSC | |
| H | .736 | .752 | 18.70 | 19.10 |
| L | .094 | .106 | 2.40 | 2.70 |
| L1 | .047 | .055 | 1.20 | 1.40 |
| L2 | .039 | .045 | 1.00 | 1.15 |
| L3 | .010 BSC | | 0.25 BSC | |
| L4 | .150 | .161 | 3.80 | 4.10 |

**1 - Gate**
**2,4 - Drain**
**3 - Source**

NOTE: ALL METAL SURFACE ARE MATTE PURE TIN PLATED EXCEPT TRIM AREA.
Pb PLATING THICKNESS (4 ~ 20 um)

## TO-247 Outline




| SYM | INCHES | | MILLIMETERS | |
|---|---|---|---|---|
| | MIN | MAX | MIN | MAX |
| A | .190 | .205 | 4.83 | 5.21 |
| A1 | .090 | .100 | 2.29 | 2.54 |
| A2 | .075 | .085 | 1.91 | 2.16 |
| b | .045 | .055 | 1.14 | 1.40 |
| b2 | .075 | .087 | 1.91 | 2.20 |
| b4 | .115 | .126 | 2.92 | 3.20 |
| C | .024 | .031 | 0.61 | 0.80 |
| D | .819 | .840 | 20.80 | 21.34 |
| D1 | .650 | .690 | 16.51 | 17.53 |
| D2 | .035 | .050 | 0.89 | 1.27 |
| E | .620 | .635 | 15.75 | 16.13 |
| E1 | .545 | .565 | 13.84 | 14.35 |
| e | .215 BSC | | 5.45 BSC | |
| J | -- | .010 | -- | 0.25 |
| K | -- | .025 | -- | 0.64 |
| L | .780 | .810 | 19.81 | 20.57 |
| L1 | .150 | .170 | 3.81 | 4.32 |
| øP | .140 | .144 | 3.55 | 3.65 |
| øP1 | .275 | .290 | 6.99 | 7.37 |
| Q | .220 | .244 | 5.59 | 6.20 |
| R | .170 | .190 | 4.32 | 4.83 |
| S | .242 BSC | | 6.15 BSC | |

**1 - Gate**
**2,4 - Drain**
**3 - Source**

NOTE: This drawing will meet all dimensions requirement of JEDEC outlines TO-247 AD (R-PSIP-F3)